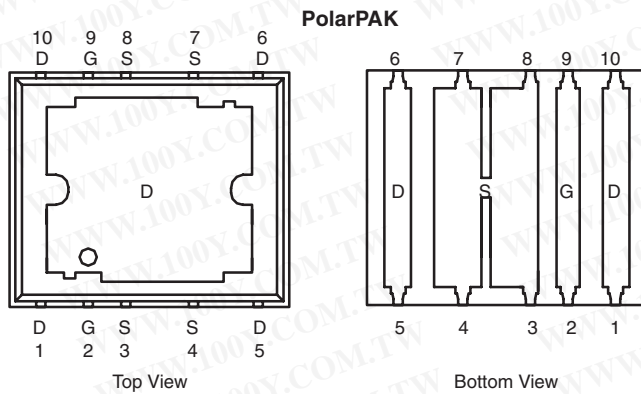


N-Channel 40-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A) ^a		Q _g (Typ.)
		Silicon Limit	Package Limit	
40	0.0055 at V _{GS} = 10 V	103	50	25 nC
	0.007 at V _{GS} = 4.5 V	91	50	

Package Drawing
www.vishay.com/doc?73398



Top surface is connected to pins 1, 5, 6, and 10

Ordering Information: SiE832DF-T1-E3 (Lead (Pb)-free)
 SiE832DF-T1-GE3 (Lead (Pb)-free and Halogen-free)

FEATURES

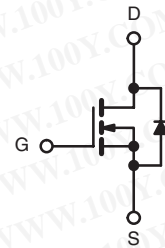
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- Ultra Low Thermal Resistance Using Top-Exposed PolarPAK[®] Package for Double-Sided Cooling
- Leadframe-Based New Encapsulated Package
 - Die Not Exposed
 - Same Layout Regardless of Die Size
- Low Q_{gd}/Q_{gs} Ratio Helps Prevent Shoot-Through
- 100 % R_g and UIS Tested
- Compliant to RoHS directive 2002/95/EC



RoHS
 COMPLIANT
 HALOGEN
FREE
 Available

APPLICATIONS

- VRM
- Point-of-Load
- Synchronous Rectification



N-Channel MOSFET

For Related Documents
www.vishay.com/ppg?74414

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted				
Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	40	V	
Gate-Source Voltage	V _{GS}	± 20	V	
Continuous Drain Current (T _J = 150 °C)	I _D	103 (Silicon Limit)		A
		50 ^a (Package Limit)		
		50 ^a		
		23.6 ^{b, c}		
Pulsed Drain Current	I _{DM}	80		A
		18.9 ^{b, c}		
Continuous Source-Drain Diode Current	I _S	50 ^a		A
		4.3 ^{b, c}		
Single Pulse Avalanche Current	I _{AS}	35		mJ
Avalanche Energy	E _{AS}	61		
Maximum Power Dissipation	P _D	104		W
		66		
		5.2 ^{b, c}		
		3.3 ^{b, c}		
Operating Junction and Storage Temperature Range	T _J , T _{stg}	- 55 to 150		°C
Soldering Recommendations (Peak Temperature) ^{d, e}		260		

Notes:

- Package limited is 50 A.
- Surface Mounted on 1" x 1" FR4 board.
- t = 10 s.
- See Solder Profile (www.vishay.com/doc?73257). The PolarPAK is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

THERMAL RESISTANCE RATINGS

Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^{a, b}	$t \leq 10$ s	R_{thJA}	20	24	°C/W
Maximum Junction-to-Case (Drain Top) ^a	Steady State	R_{thJC} (Drain)	1	1.2	
Maximum Junction-to-Case (Source) ^{a, c}		R_{thJC} (Source)	2.8	3.4	

Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
 b. Maximum under Steady State conditions is 68 °C/W.
 c. Measured at source pin (on the side of the package).

SPECIFICATIONS $T_J = 25$ °C, unless otherwise noted

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0$ V, $I_D = 250$ μ A	40			V	
V_{DS} Temperature Coefficient	$\Delta V_{DS}/T_J$	$I_D = 250$ μ A		43.1		mV/°C	
$V_{GS(th)}$ Temperature Coefficient	$\Delta V_{GS(th)}/T_J$		-6.9				
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250$ μ A	1.5	2.2	3.0	V	
Gate-Source Leakage	I_{GSS}	$V_{DS} = 0$ V, $V_{GS} = \pm 20$ V			± 100	nA	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 40$ V, $V_{GS} = 0$ V			1	μ A	
		$V_{DS} = 40$ V, $V_{GS} = 0$ V, $T_J = 55$ °C			10		
On-State Drain Current ^a	$I_{D(on)}$	$V_{DS} \geq 5$ V, $V_{GS} = 10$ V	25			A	
Drain-Source On-State Resistance ^a	$R_{DS(on)}$	$V_{GS} = 10$ V, $I_D = 14$ A		0.0046	0.0055	Ω	
		$V_{GS} = 4.5$ V, $I_D = 12$ A		0.0058	0.007		
Forward Transconductance ^a	g_{fs}	$V_{DS} = 15$ V, $I_D = 13.6$ A		86		S	
Dynamic^b							
Input Capacitance	C_{iss}	$V_{DS} = 20$ V, $V_{GS} = 0$ V, $f = 1$ MHz		3800		pF	
Output Capacitance	C_{oss}		510				
Reverse Transfer Capacitance	C_{rss}		160				
Total Gate Charge	Q_g	$V_{DS} = 20$ V, $V_{GS} = 10$ V, $I_D = 20$ A		51	77	nC	
			$V_{DS} = 20$ V, $V_{GS} = 4.5$ V, $I_D = 20$ A		25		38
							12
Gate-Source Charge	Q_{gs}			7			
Gate-Drain Charge	Q_{gd}						
Gate Resistance	R_g	$f = 1$ MHz		1.1	1.7	Ω	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 20$ V, $R_L = 2$ Ω $I_D \cong 10$ A, $V_{GEN} = 4.5$ V, $R_g = 1$ Ω		45	70	ns	
Rise Time	t_r			260	400		
Turn-Off Delay Time	$t_{d(off)}$			35	55		
Fall Time	t_f			55	85		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 20$ V, $R_L = 2$ Ω $I_D \cong 10$ A, $V_{GEN} = 10$ V, $R_g = 1$ Ω		15	25	ns	
Rise Time	t_r			30	45		
Turn-Off Delay Time	$t_{d(off)}$			35	55		
Fall Time	t_f			10	15		
Drain-Source Body Diode Characteristics							
Continuous Source-Drain Diode Current	I_S	$T_C = 25$ °C			50	A	
Pulse Diode Forward Current ^a	I_{SM}				80		
Body Diode Voltage	V_{SD}	$I_S = 10$ A		0.8	1.2	V	
Body Diode Reverse Recovery Time	t_{rr}	$I_F = 10$ A, $di/dt = 100$ A/ μ s, $T_J = 25$ °C		85	130	ns	
Body Diode Reverse Recovery Charge	Q_{rr}			110	170	nC	
Reverse Recovery Fall Time	t_a			64		ns	
Reverse Recovery Rise Time	t_b			21			

Notes:

- a. Pulse test; pulse width ≤ 300 μ s, duty cycle ≤ 2 %
 b. Guaranteed by design, not subject to production testing.

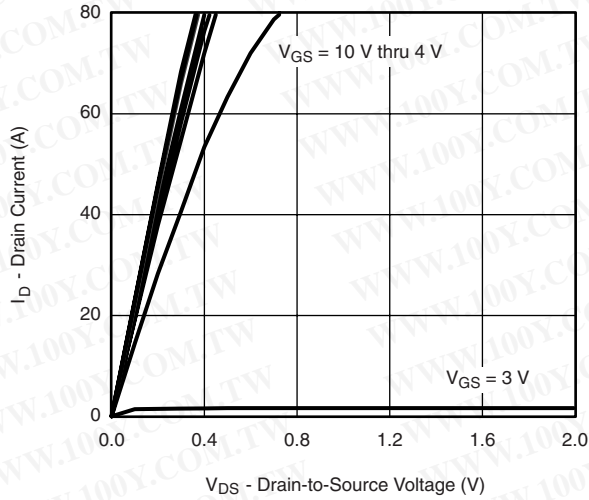
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



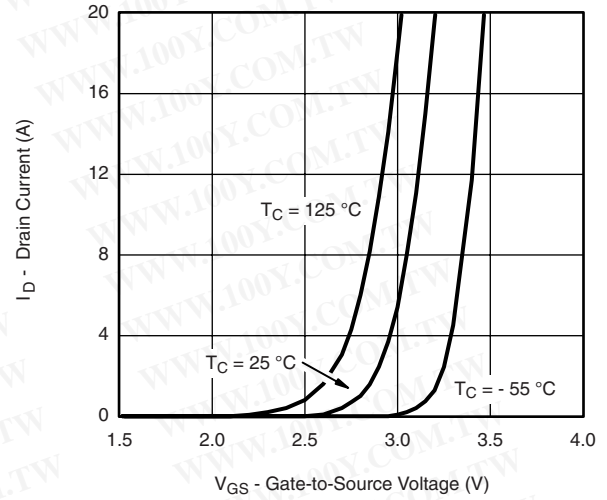
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SiE832DF
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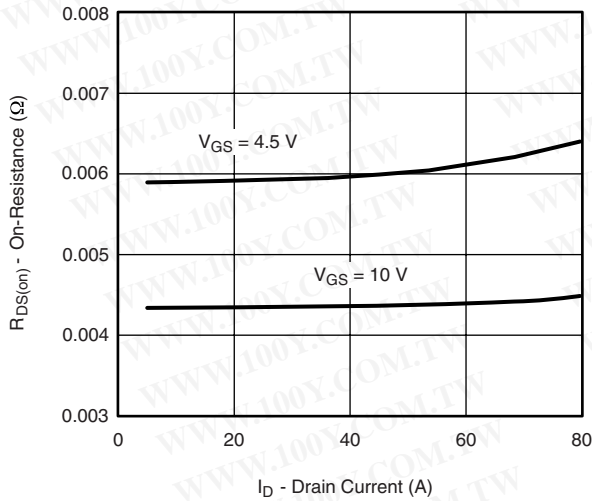
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



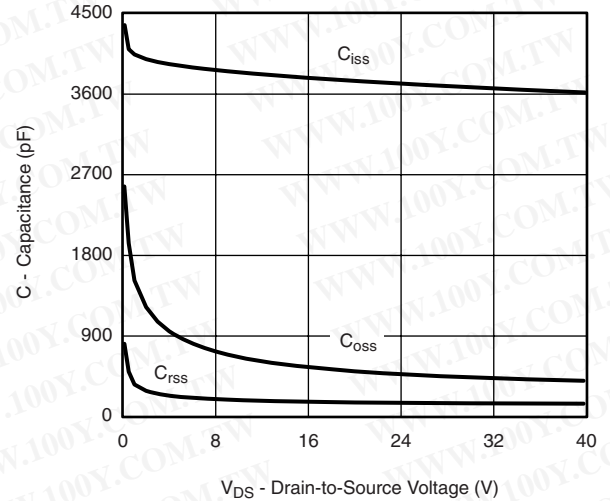
Output Characteristics



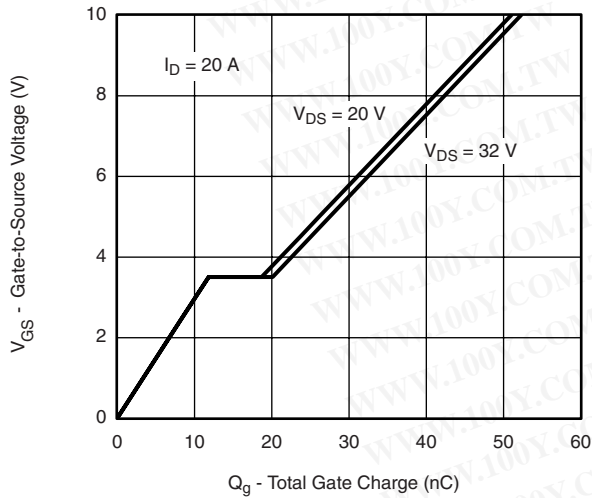
Transfer Characteristics



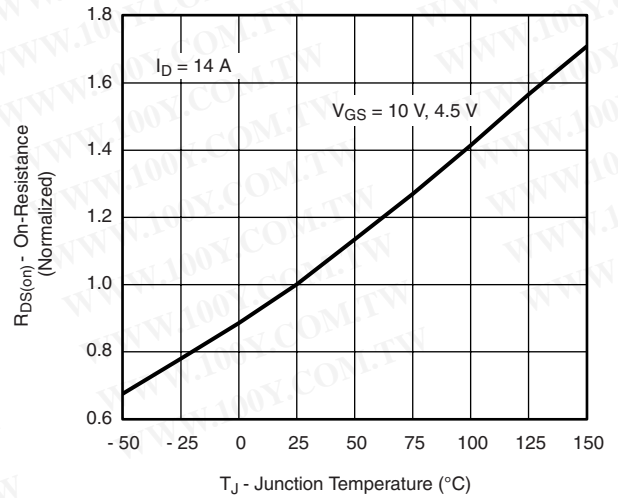
On-Resistance vs. Drain Current



Capacitance



Gate Charge



On-Resistance vs. Junction Temperature

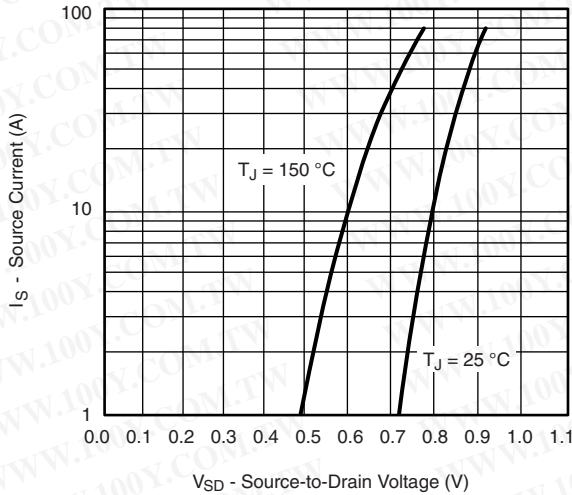
SiE832DF

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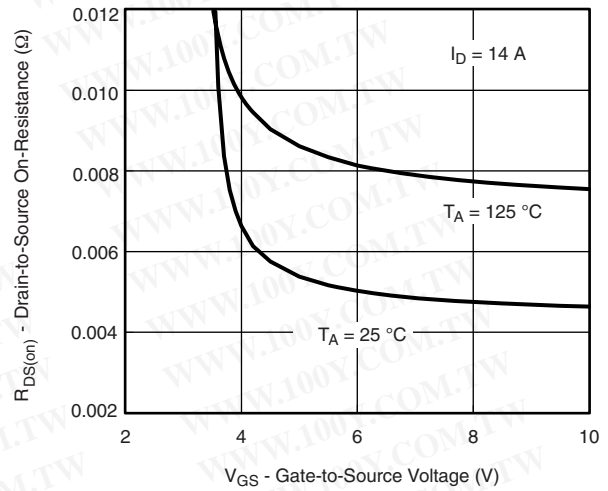
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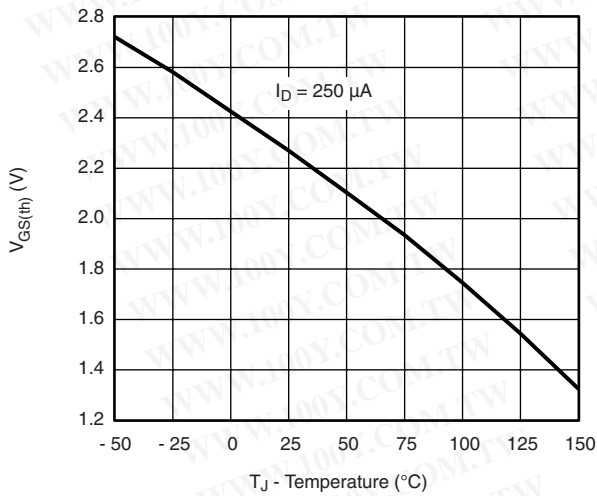
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



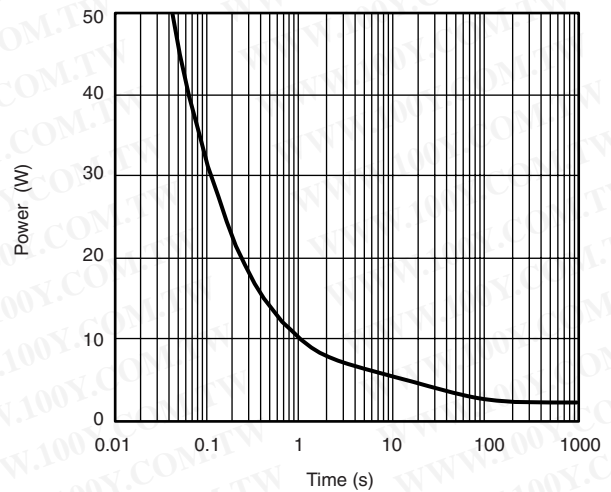
Source-Drain Diode Forward Voltage



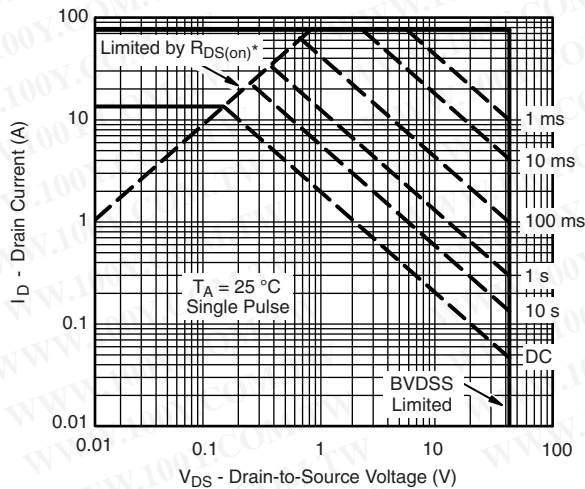
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



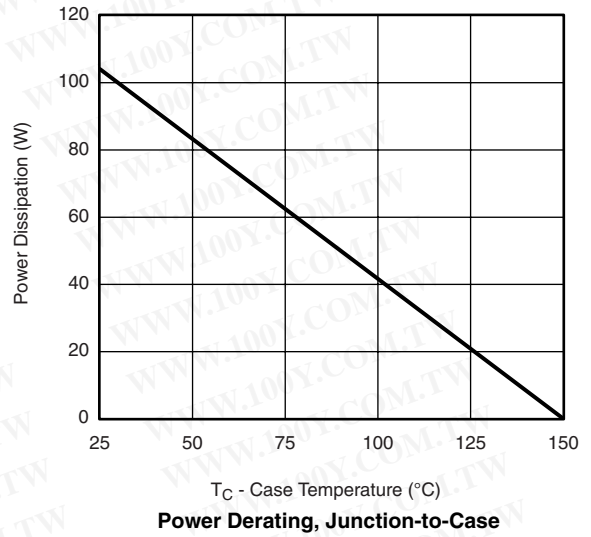
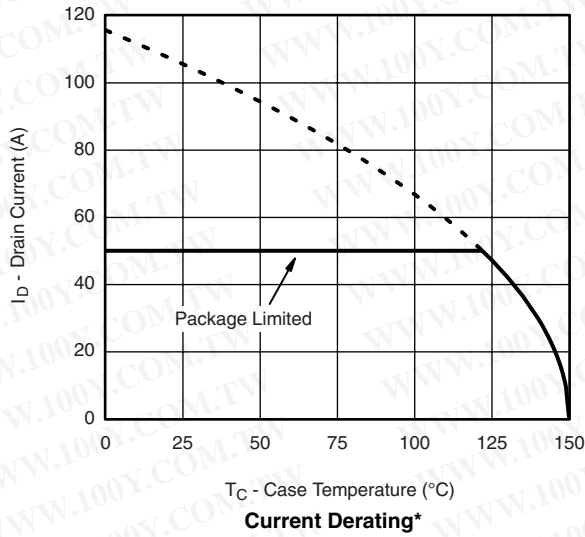
Single Pulse Power, Junction-to-Ambient



* $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified

Safe Operating Area, Junction-to-Ambient

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

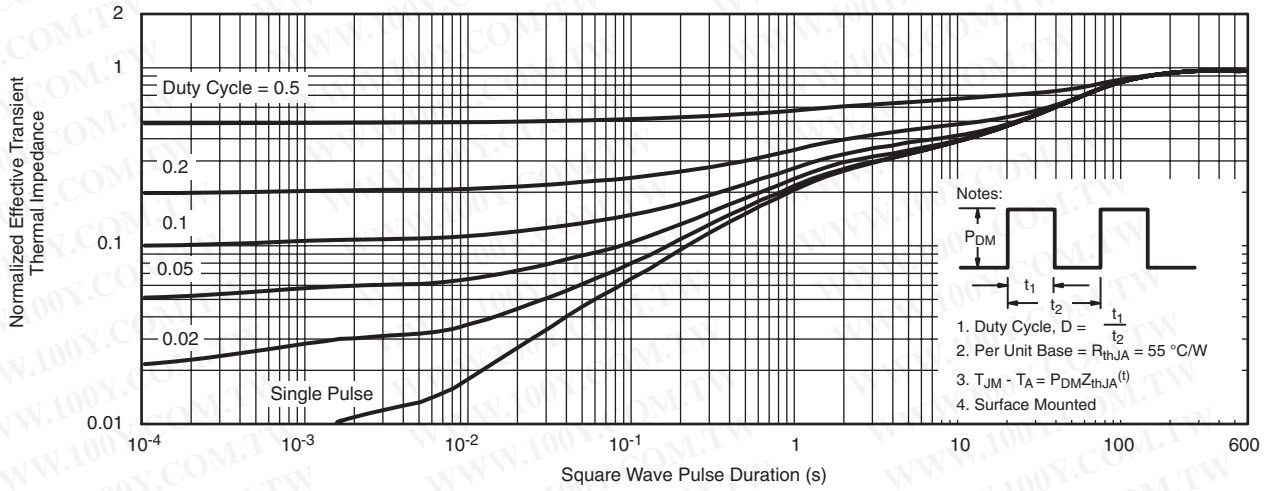


* The power dissipation P_D is based on $T_{J(max)} = 150\text{ °C}$, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

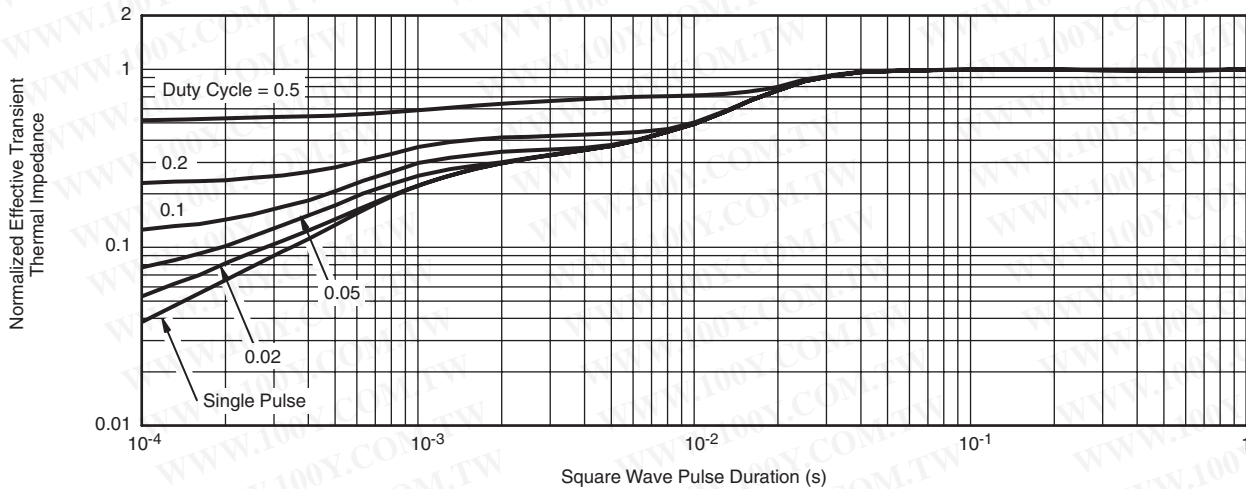
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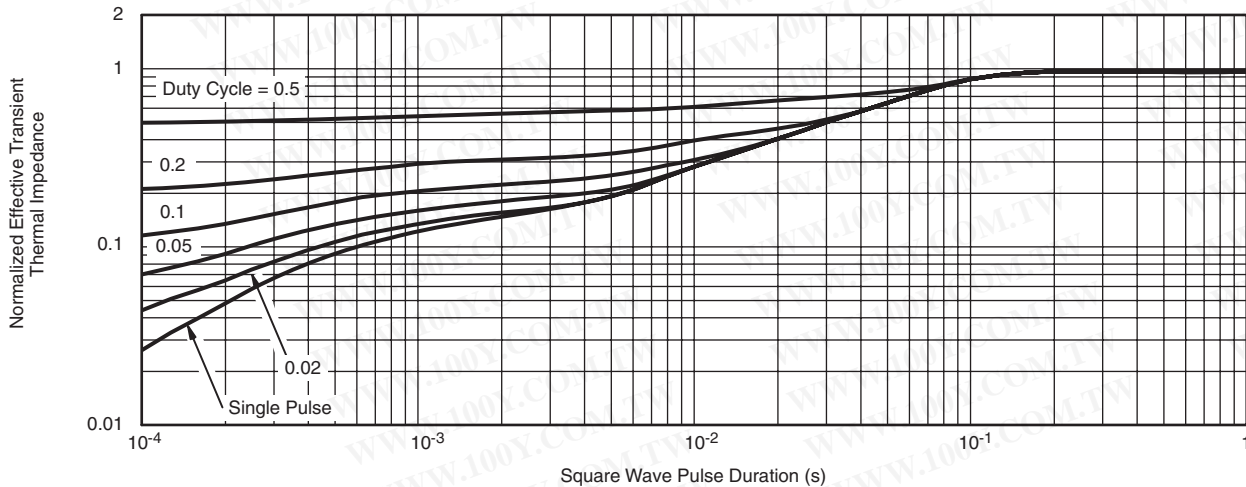
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case (Drain Top)



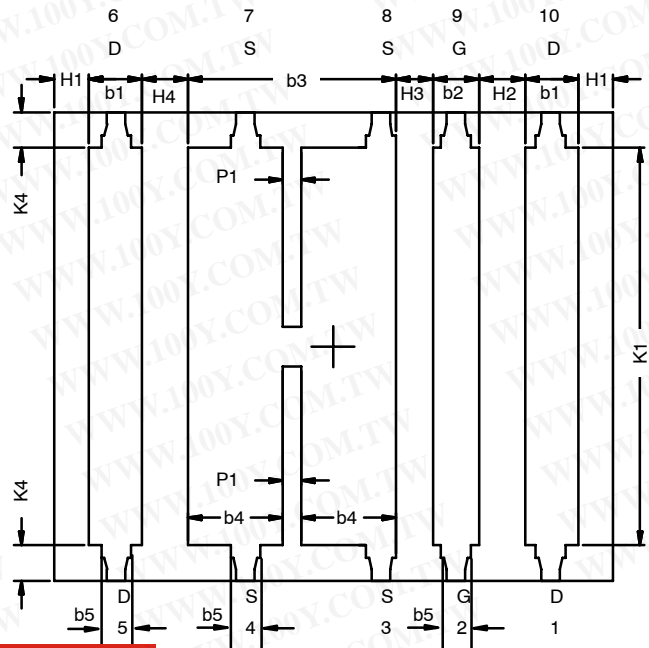
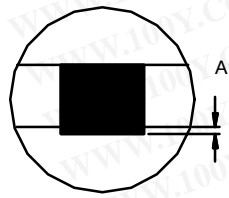
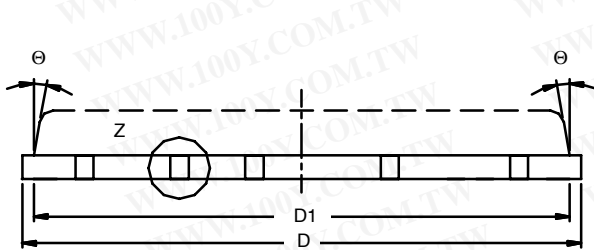
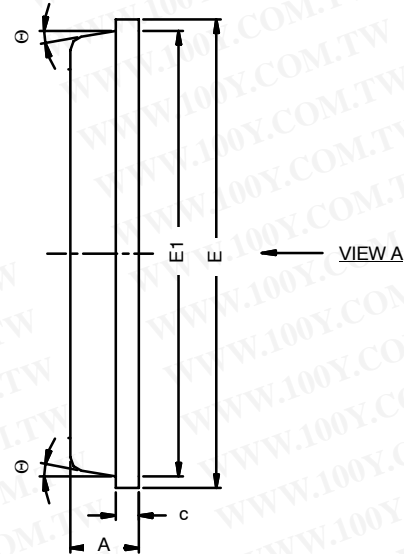
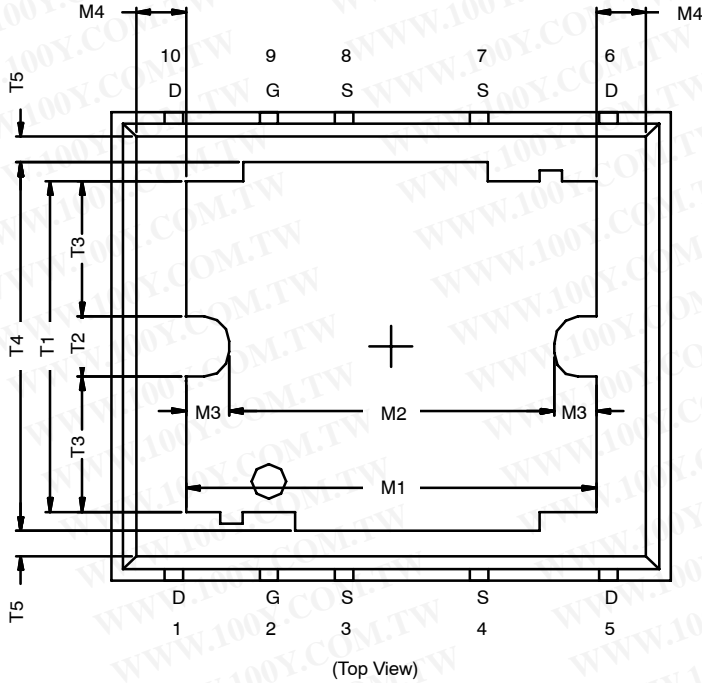
Normalized Thermal Transient Impedance, Junction-to-Source

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?74414.



PolarPAK™ (Option S)

Product datasheet/information page contain links to applicable package drawing.



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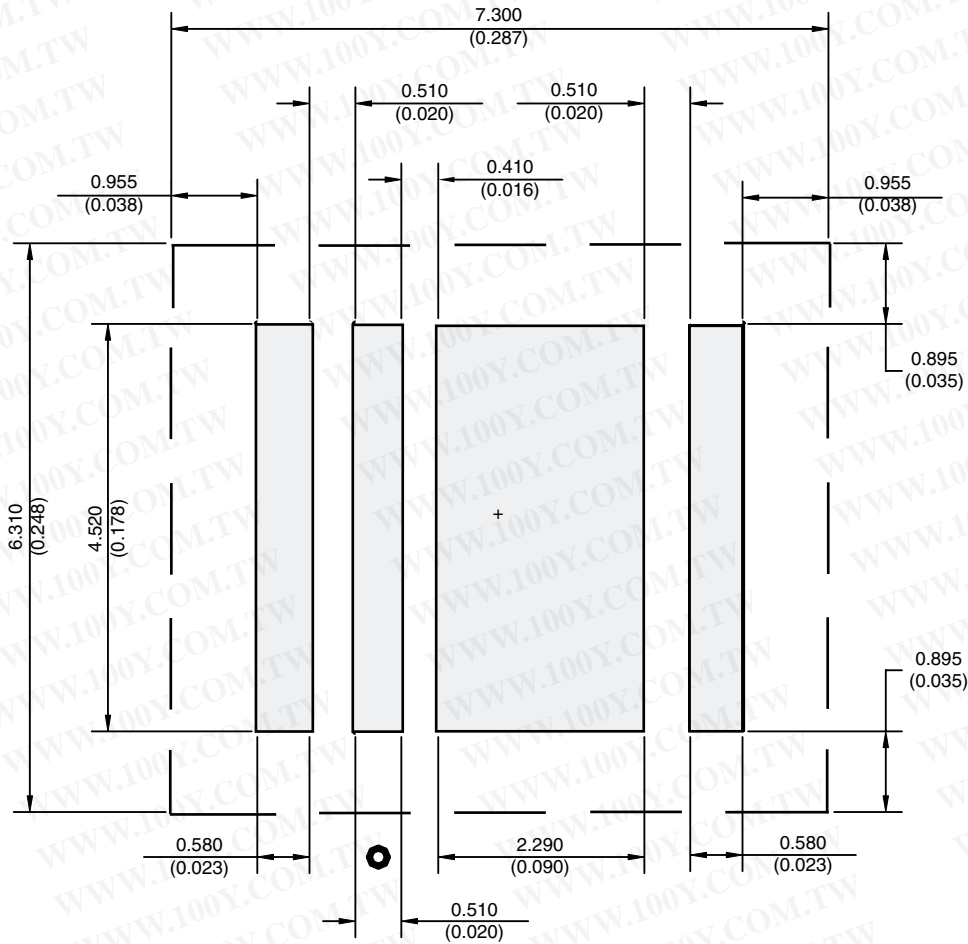
Dim	MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max
A	0.75	0.80	0.85	0.030	0.031	0.033
A1	0.00	-	0.05	0.000	-	0.002
b1	0.48	0.58	0.68	0.019	0.023	0.027
b2	0.41	0.51	0.61	0.016	0.020	0.024
b3	2.19	2.29	2.39	0.086	0.090	0.094
b4	0.89	1.04	1.19	0.035	0.041	0.047
b5	0.23	0.33	0.43	0.009	0.013	0.017
c	0.20	0.25	0.30	0.008	0.010	0.012
D	6.00	6.15	6.30	0.236	0.242	0.248
D1	5.74	5.89	6.04	0.226	0.232	0.238
E	5.01	5.16	5.31	0.197	0.203	0.209
E1	4.75	4.90	5.05	0.187	0.193	0.199
H1	0.23	-	-	0.009	-	-
H2	0.45	-	0.56	0.020	-	0.022
H3	0.31	0.41	0.51	0.012	0.016	0.020
H4	0.45	-	0.56	0.020	-	0.022
K1	4.22	4.37	4.52	0.166	0.172	0.178
K4	0.24	-	-	0.009	-	-
M1	4.30	4.50	4.70	0.169	0.177	0.185
M2	3.43	3.58	3.73	0.135	0.141	0.147
M3	0.22	-	-	0.009	-	-
M4	0.05	-	-	0.002	-	-
P1	0.15	0.20	0.25	0.006	0.008	0.010
T1	3.48	3.64	4.10	0.137	0.143	0.150
T2	0.56	0.76	0.95	0.22	0.030	0.037
T3	1.20	-	-	0.051	-	-
T4	3.90	-	-	0.154	-	-
T5	0	0.18	0.36	0.000	0.007	0.014
Θ	0°	10°	12°	0°	10°	12°
ECN: S-51049 Rev. B, 13-Jun-05 DWG: 5947						

Note: Millimeters govern over inches

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RECOMMENDED MINIMUM PADS FOR PolarPAK® Option L and S



Recommended Minimum for PolarPAK Option L and S
Dimensions in mm/(Inches)
No External Traces within Broken Lines
Dot indicates Gate Pin (Part Marking)

APPLICATION NOTE

Return to Index

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